Characteristics STPS2H100ZF

1 Characteristics

Table 2: Absolute ratings (limiting values at 25 °C, unless otherwise specified)

Symbol	Parameter	Value	Unit	
V _{RRM}	Repetitive peak reverse voltage	100	V	
I _{F(AV)}	Average forward current $ T_{L} = 140 ^{\circ}\text{C/} $ $ \delta = 0.5, \text{ square wave} $		2	Α
I _{FSM}	Surge non repetitive forward current	50	Α	
P _{ARM}	Repetitive peak avalanche power $t_p = 10 \mu s, T_j = 125 ^{\circ}C$		105	W
T _{stg}	Storage temperature range	-65 to +175	°C	
Tj	Maximum operating junction temperatu	-40 to +175		

Notes:

Table 3: Thermal parameters

Symbol	Parameter	Max. value	Unit
R _{th(j-l)}	Junction to lead	20	°C/W

Table 4: Static electrical characteristics

Symbol	Parameter	Test cor	nditions	Min.	Тур.	Max.	Unit
I _R ⁽¹⁾	Poverse leekage ourrent	T _j = 25 °C	V V	1		1	μΑ
IR ^(*)	Reverse leakage current	T _j = 125 °C	= 125 °C V _R = V _{RRM}		0.2	0.5	mA
		T _j = 25 °C		-		0.86	
V (2)	Forward voltage drop $T_j = 2$	T _j = 125 °C	I _F = 2 A	-	0.65	0.70	V
V _F ⁽²⁾		T _j = 25 °C	I _F = 4 A	-		0.96	V
		T _j = 125 °C		-	0.75	0.83	

Notes:

 $^{(1)}$ Pulse test: t_p = 5 ms, δ < 2%

To evaluate the conduction losses, use the following equation:

$$P = 0.57 \times I_{F(AV)} + 0.065 \times I_{F^{2}(RMS)}$$

For more information, please refer to the following application notes related to the power losses.

- AN604 (Calculation of conduction losses in a power rectifier)
- AN4021 (Calculation of reverse losses in a power diode)

 $^{^{(1)}(}dP_{tot}/dT_j) < (1/R_{th(j-a)})$ condition to avoid thermal runaway for a diode on its own heatsink.

⁽²⁾Pulse test: t_p = 380 μs, δ < 2%

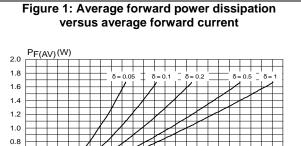
STPS2H100ZF Characteristics

1.1 Characteristics (curves)

0.6

0.4

0.0 0.2 0.4 0.6 0.8 1.0



1.2

1.8 2.0 2.2

1.6

100

1000

Figure 2: Average forward current versus ambient temperature ($\delta = 0.5$) $I_{F(AV)}(A)$ $R_{th(j-a)} = R_{th(j-l)}$ 6 5 3 2 1 T_{amb}(°C) 0 25 50 75 0 100 125 150 175

Figure 3: Normalized avalanche power derating versus pulse duration (T_j = 125 °C)

PARM(tp)
PARM(10 µs)

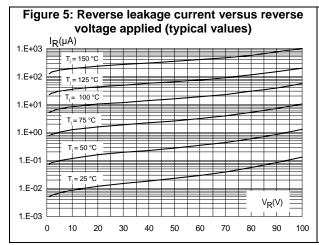
0.1

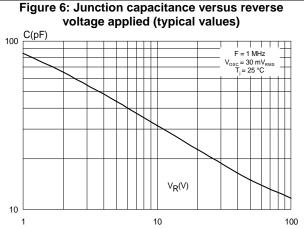
0.01

0.001

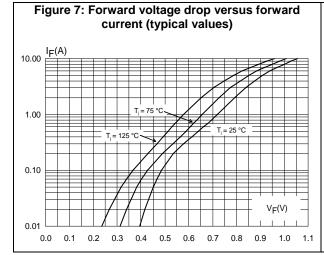
10

Figure 4: Relative variation of thermal impedance junction to lead versus pulse duration $Z_{th(j-l)}/R_{th(j-l)}$ 1.0 0.9 0.8 0.7 0.6 0.5 0.4 0.3 0.2 0.1 0.0 1.E-04 1.E-02 1.E-01 1.E+00 1.E+01





Characteristics STPS2H100ZF



Versus copper surface under each lead (typical values)

Rth(j-a)(C/W)

250

Rth(j-a)(C/W)

200

150

Epoxy printed board FR4, e_{Cu} = 35 μm

50

0.0 0.5 1.0 1.5 2.0 2.5 3.0 3.5 4.0 4.5 5.0

Figure 8: Thermal resistance junction to ambient

STPS2H100ZF Package information

2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: **www.st.com**. ECOPACK® is an ST trademark.

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)

2.1 SOD123Flat package information

Figure 9: SOD123Flat package outline

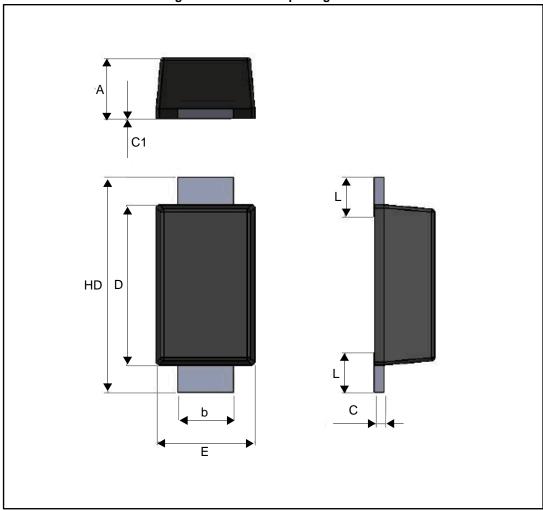
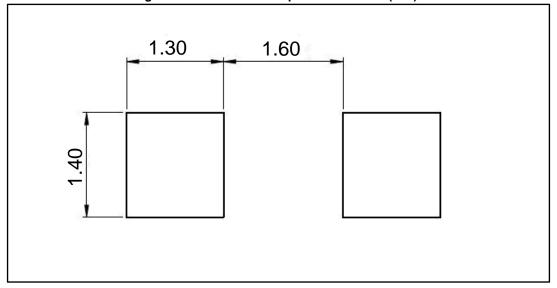


Table 5: SOD123Flat package mechanical data

	Dimensions			
Ref.	Millimeters			
	Min.	Тур.	Max.	
A	0.86	0.98	1.10	
b	0.80	0.90	1.00	
С	0.08	0.15	0.25	
c1	0.00		0.10	
D	2.50	2.60	2.70	
Е	1.50	1.60	1.80	
HD	3.30	3.50	3.70	
L	0.45	0.65	0.85	

Figure 10: SOD123Flat footprint dimensions (mm)



3 Ordering information

Table 6: Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
STPS2H100ZF	2H1	SOD123Flat	12.5 mg	3000	Tape and reel

4 Revision history

Table 7: Document revision history

Date		Revision	Changes
	19-Aug-2016	1	Initial release.



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